

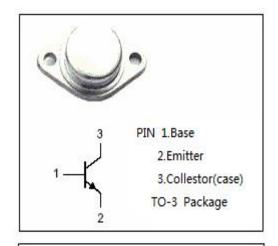
isc Silicon NPN Power Transistor

DESCRIPTION

- · High Breakdown Voltage-
 - : V_{CBO}= 1500V (Min)
- · High Switching Speed
- · Wide Area of Safe Operation
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

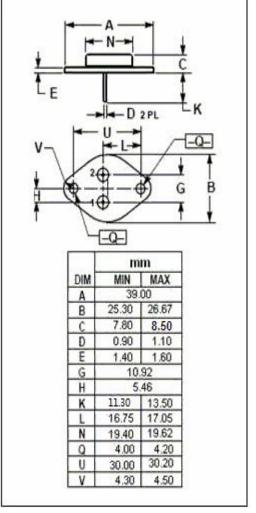
APPLICATIONS

• Designed for switching regulator applications.



ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{CBO}	Collector-Base Voltage	1500	V	
V _{CER}	Collector-Emitter Voltage	800	V	
V _{EBO}	Emitter-Base Voltage	5	V	
Ic	Collector Current- Continuous	5	Α	
I _{CP}	Collector Current-Pulse	10	А	
Pc	Collector Power Dissipation @ T _C T _C =25 °C	50	W	
TJ	Junction Temperature 150		$^{\circ}$ C	
T _{stg}	Storage Temperature Range	-65~150	$^{\circ}\mathbb{C}$	





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2SD1168

ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT		
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = 1mA; I _C = 0	5			V		
V _{CER(SUS)}	Collector-Emitter Sustaining Voltage	I_{C} = 50mA; R_{BE} = 10 Ω ; L= 2mH	800			V		
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 2A; I _B = 1A			1.0	V		
V _{BE(sat)}	Base-Emitter Saturation Voltage	Ic= 2A; I _B = 1A			1.5	V		
Ісво	Collector Cutoff Current	V _{CB} = 750V; I _E = 0			50	μА		
		V _{CB} = 1500V; I _E = 0			1	mA		
h _{FE}	DC Current Gain	I _C = 1A; V _{CE} = 4V	9		25			
t _f	Fall Time	1.454 0.04 0.74			0.5	μ \$		
t _{stg}	Storage Time	I _C = 1.5A , I _{B1} = 0.2A, I _{B2} = 0.7A		2.0		μS		

♦ h_{FE} classifications

Q	Р		
9-18	15-25		

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